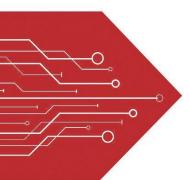
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Product data sheet

www.msksemi.com





Features

- Solid-state silicon-avalanche technology
- Low operating and clamping voltage
- Up to four I/O Lines of Protection
- Ultra low capacitance: 0.5pF typical(I/O to I/O)
- Low Leakage
- Low operating voltage:5V
- Flow-Through design

IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 5A (8/20μs)

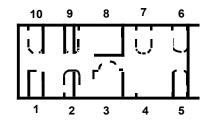
Mechanical Characteristics

- DFN2510-10L
- Molding compound flammability rating: UL 94V-0
- Marking: Marking Code
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Applications

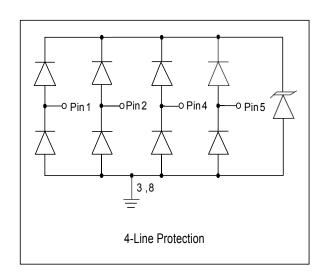
- Digital Visual Interface(DVI)
- MDDI Ports
- DisplayPortTM Interface
- **PCI Express**
- High Definition Multi-Media Interface(HDMI)
- eSATA Interfaces

DFN2510-10L



| Pin | Identificaion |
|----------|--|
| 1,2,4,5 | Input Lines |
| 6,7,9,10 | Output Lines (No Internal Connection) |
| 3,8 | Ground |

Circuit Diagram







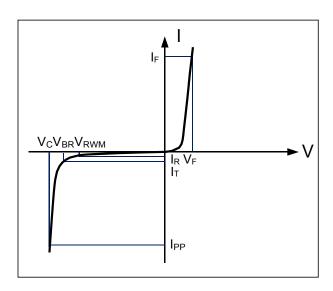




| Rating | Symbol | Value | Units |
|---|------------------|----------------|-------|
| Peak Pulse Power (t _p =8/20μs) | P _{PP} | 150 | Watts |
| Peak Pulse Current (t _p =8/20μs) | I _{pp} | 5 | А |
| ESD per IEC 61000-4-2(Air) ESD per IEC 61000-4-2(contact) | V _{ESD} | +/-17 +/-12 | kV |
| Operating Temperature | TJ | -55 to + 125 | °C |
| Storage Temperature | T _{STG} | -55 to +150 | °C |

Electrical Parameters (T=25°C)

| Symbol | Parameter |
|-----------------|--|
| I PP | Maximum Reverse Peak Pulse Current |
| Vc | Clamping Voltage @ IPP |
| VRWM | Working Peak Reverse Voltage |
| IR | Maximum Reverse Leakage Current @ VRWM |
| V _{BR} | Breakdown Voltage @ I⊤ |
| lτ | Test Current |
| lF | Forward Current |
| VF | Forward Voltage @ I _F |



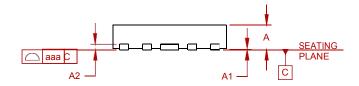
Electrical Characteristics

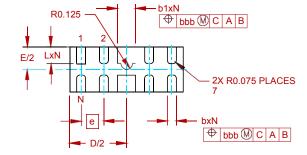
| Parameter | Symbol | Conditions | Minimum | Typical | Maximum | Units |
|---------------------------|------------------|--|---------|---------|---------|-------|
| Reverse Stand-Off Voltage | V _{RWM} | Any I/O pin to ground | | | 5.0 | V |
| Reverse Breakdown Voltage | V _{BR} | I _t = 1mA Any I/O pin to ground | 6.0 | | | V |
| Reverse Leakage Current | I _R | V _{RWM} = 5V, T=25°C Any I/O pin to ground | | | 1 | μA |
| Clamping Voltage | Vc | I _{pp} =5A, t _p =8/20µs Any I/O pin to ground | | | 15 | V |
| | | V _R = 0V, f = 1MHz I/O pin to GND | | | 0.8 | pF |
| Junction Capacitance | C _j | V _R = 0V, f = 1MHz Between I/O pins | | 0.3 | | pF |



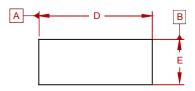






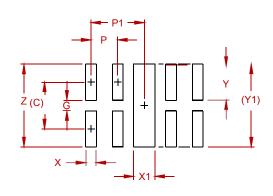


Dimensions in millimeters



| DIMENSI ONS | | | | | | |
|-------------|----------|-------------|------|------|------|-------|
| DIM INCHES | | MILLIMETERS | | | | |
| J | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | .020 | .023 | .026 | 0.50 | 0.58 | 0.65 |
| A1 | 0.00 | .001 | .002 | 0.00 | 0.03 | 0.05 |
| A2 | (.005) | | (0 | .13) | | |
| b | .006 | .008 | .010 | 0.15 | 0.20 | 0.25 |
| b1 | .014 | .016 | .018 | 0.35 | 0.40 | 0.45 |
| D | .094 | .098 | .102 | 2.40 | 2.50 | 2.60 |
| E | .035 | .039 | .043 | 0.90 | 1.00 | 1.10 |
| е | .020 BSC | | 0.50 | BSC | | |
| L | .012 | .015 | .017 | 0.30 | 0.38 | 0.425 |
| N | 8 | | | 8 | | |
| aaa | .003 | | 0.08 | | | |
| bbb | .004 | | | 0.10 | | |

Suggested Pad Layout



| DIMENSIONS | | | |
|------------|--------|-------------|--|
| DIM | INCHES | MILLIMETERS | |
| С | (.034) | (0.875) | |
| G | .008 | 0.20 | |
| Р | .020 | 0.50 | |
| P1 | .039 | 1.00 | |
| Х | .008 | 0.20 | |
| X1 | .016 | 0.40 | |
| Υ | .027 | 0.675 | |
| Y1 | (.061) | (1.55) | |
| Z | .061 | 1.55 | |

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES). THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

| P/N | PKG | QTY |
|-------------|-------------|------|
| ESD5344D-MS | DFN2510-10L | 3000 |



Semiconductor

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